# **CMOS Boost Converter -**White LED Driver

#### Description

The CAT4137 is a DC/DC step-up converter that delivers a regulated output current. Operation at a constant switching frequency of 1 MHz allows the device to be used with small value external ceramic capacitors and inductor.

The device drives a string of white LEDs connected in series and provides the regulated current to control the LEDs with inherent uniform brightness and matching. An external resistor R1 sets the output current and allows up to 30 mA current to be supported over a wide range of input supply voltages from 2.2 V to 5.5 V, making the device ideal for battery-powered applications.

LED dimming can be done by using a DC voltage, a logic signal, or a pulse width modulation (PWM) signal. The shutdown control pin allows the device to be placed in power-down mode with "zero" quiescent current.

In addition to thermal protection and overload current limiting, the device also enters a very low power operating mode during "Open LED" fault conditions. The device is housed in a low profile (1 mm max height) 5-lead thin SOT23 package for space critical applications.

#### **Features**

- Drives up to 5 White LEDs from 3 V
- Power Efficiency up to 87%
- Low Quiescent Ground Current 0.1 mA
- Adjustable Output Current (up to 30 mA
- High Frequency 1 MHz Operation
- "Zero" Current Shutdown Mode
- Operates Down to 2 V (from Two AA Batteries)
- Soft Start Power-up
- Open LED Low Power Mode
- Automatic Shutdown at 1.9 V (UVLO)
- Thermal Shutdown Protection
- Thin SOT23 5-lead (1 mm Max Height)
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Applications**

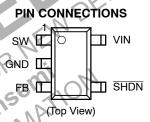
- LCD Backlighting
- Cellular Phones
- Handheld Devices
- Digital Cameras



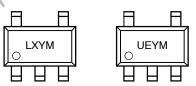
# ON Semiconductor®

http://onsemi.com





#### MARKING DIAGRAMS



LX = CAT4137TD-T3

UE = CAT4137TD-GT3

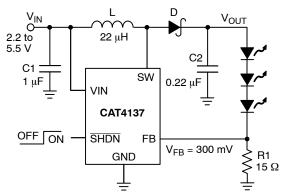
Y = Production Year (Last Digit)

M = Production Month (1-9, A, B, C)

#### **ORDERING INFORMATION (Note 3)**

Device	Package	Shipping (Note 4)
CAT4137TD-T3	TSOT-23	3,000/
(Note 1)	(Pb-Free)	Tape & Reel
CAT4137TD-GT3	TSOT-23	3,000/
(Note 2)	(Pb-Free)	Tape & Reel

- 1. Matte-Tin Plated Finish (RoHS-compliant).
- 2. NiPdAu Plated Finish (RoHS-compliant)
- 3. For detailed information and a breakdown of device nomenclature and numbering systems, please see the ON Semiconductor Device Nomenclature document, TND310/D, available at www.onsemi.com
- 4. For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



L: Murata LQH32CN220

D: Central CMDSH2-3 (rated 30 V)

Figure 1. Typical Application Circuit

**Table 1. ABSOLUTE MAXIMUM RATINGS** 

Parameter	Rating
VIN, FB voltage	-0.3 to +7 V
SHDN voltage	-0.3 to +7 V
SW voltage	-0.3 to +40 V
Storage Temperature Range	-65 to +160 °C
Junction Temperature Range	-40 to +150 °C
Lead Temperature	300 °C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 2. RECOMMENDED OPERATING CONDITIONS

Parameter	Range	Unit
VIN	2.2 to 5.5	V
SW pin voltage	0 to 24	V
Ambient Temperature Range	-40 to +85	°C
LED Bias Current	1 to 30	mA
THIS DEV. PERRES		

#### **Table 3. ELECTRICAL OPERATING CHARACTERISTICS**

 $(V_{IN} = 3.6 \text{ V}, \text{ ambient temperature of } 25^{\circ}\text{C} \text{ (over recommended operating conditions unless otherwise specified))}$ 

VFB = 0.4 V (not switching)	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VFB         FB Pin Voltage         3 LEDs with I <sub>LED</sub> = 20 mA         285         300         315         m <sup>N</sup> I <sub>FB</sub> FB pin input leakage         0.1         1         μ <sup>A</sup> I <sub>LED</sub> Programmed LED Current         R1 = 10 Ω R1 = 15 Ω R1 = 20 Ω         28.5 19 20 21 14.25         30 21 15.75           V <sub>IH</sub> V <sub>IL</sub> SHDN Logic High SHDN Logic Low         Enable Threshold Level Shutdown Threshold Level         0.4         0.8 0.7         1.5         V           F <sub>SW</sub> Switching Frequency         0.7         1.0         1.3         MH           I <sub>LIM</sub> Switch Current Limit         250         300         400         m/           R <sub>SW</sub> Switch "On" Resistance         I <sub>SW</sub> = 100 mA         1.0         2.0         Ω           I <sub>LEAK</sub> Switch Leakage Current         Switch Off, V <sub>SW</sub> = 5 V         1         5         μ <sup>A</sup> T <sub>HYS</sub> Thermal Hysteresis         20         °C           η         Efficiency         Typical Application Circuit         86         %           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1,9         V	VFB         FB Pin Voltage         3 LEDs with I <sub>LED</sub> = 20 mA         285         300         315           I <sub>FB</sub> FB pin input leakage         0.1         1           I <sub>LED</sub> Programmed LED Current         R1 = 10 Ω R1 = 15 Ω R1 = 15 Ω R1 = 20 Ω         28.5 19 20 21 14.25         30 21 15.75           V <sub>IH</sub> V <sub>IL</sub> SHDN Logic High SHDN Logic Low         Enable Threshold Level Shutdown Threshold Level         0.4         0.8 0.7         1.5           F <sub>SW</sub> Switching Frequency         0.7         1.0         1.3           I <sub>LIM</sub> Switch Current Limit         250         300         400           R <sub>SW</sub> Switch "On" Resistance         I <sub>SW</sub> = 100 mA         1.0         2.0           I <sub>LEAK</sub> Switch Leakage Current         Switch Off, V <sub>SW</sub> = 5 V         1         5           T <sub>SD</sub> Thermal Shutdown         150         150           T <sub>HYS</sub> Thermal Hysteresis         20           η         Efficiency         Typical Application Circuit         86           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1,9	IQ	Operating Current	V <sub>FB</sub> = 0.3 V V <sub>FB</sub> = 0.4 V (not switching)				mA
IFB   FB pin input leakage	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I <sub>SD</sub>	Shutdown Current	V <sub>SHDN</sub> = 0 V		0.1	1	μΑ
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V <sub>FB</sub>	FB Pin Voltage	3 LEDs with I <sub>LED</sub> = 20 mA	285	300	315	mV
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I <sub>FB</sub>	FB pin input leakage			0.1	1	μА
V <sub>IL</sub> SHDN Logic Low         Shutdown Threshold Level         0.4         0.7           F <sub>SW</sub> Switching Frequency         0.7         1.0         1.3         MH           I <sub>LIM</sub> Switch Current Limit         250         300         400         m/           R <sub>SW</sub> Switch "On" Resistance         I <sub>SW</sub> = 100 mA         1.0         2.0         Ω           I <sub>LEAK</sub> Switch Leakage Current         Switch Off, V <sub>SW</sub> = 5 V         1         5         μA           T <sub>SD</sub> Thermal Shutdown         150         °C         °C           T <sub>HYS</sub> Thermal Hysteresis         20         °C           η         Efficiency         Typical Application Circuit         86         %           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1.9         V	VIL         SHDN Logic Low         Shutdown Threshold Level         0.4         0.7         Logic Low         Shutdown Threshold Level         0.4         0.7         Logic Low         Switch Switch Low         Logic Low </td <td>I<sub>LED</sub></td> <td>Programmed LED Current</td> <td>R1 = 15 Ω</td> <td>19</td> <td>20</td> <td>21</td> <td>mA</td>	I <sub>LED</sub>	Programmed LED Current	R1 = 15 Ω	19	20	21	mA
I <sub>LIM</sub>   Switch Current Limit   250   300   400   m/s     R <sub>SW</sub>   Switch "On" Resistance   I <sub>SW</sub> = 100 mA   1.0   2.0   Ω     I <sub>LEAK</sub>   Switch Leakage Current   Switch Off, V <sub>SW</sub> = 5 V   1   5   μ/s     T <sub>SD</sub>   Thermal Shutdown   150   °C     T <sub>HYS</sub>   Thermal Hysteresis   20   °C     η   Efficiency   Typical Application Circuit   86   %   6   %     V <sub>UVLO</sub>   Undervoltage Lockout (UVLO) Threshold   1.9   V	ILIM         Switch Current Limit         250         300         400           R <sub>SW</sub> Switch "On" Resistance         I <sub>SW</sub> = 100 mA         1.0         2.0           I <sub>LEAK</sub> Switch Leakage Current         Switch Off, V <sub>SW</sub> = 5 V         1         5           T <sub>SD</sub> Thermal Shutdown         150         150           T <sub>HYS</sub> Thermal Hysteresis         20         20           η         Efficiency         Typical Application Circuit         86           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1,9	V <sub>IH</sub> V <sub>IL</sub>	SHDN Logic High SHDN Logic Low		0.4		1.5	V
$R_{SW}$ Switch "On" Resistance $I_{SW} = 100 \text{ mA}$ 1.0     2.0 $\Omega$ $I_{LEAK}$ Switch Leakage Current     Switch Off, $V_{SW} = 5 \text{ V}$ 1     5 $\mu A$ $T_{SD}$ Thermal Shutdown     150     °C $T_{HYS}$ Thermal Hysteresis     20     °C $\eta$ Efficiency     Typical Application Circuit     86     % $V_{UVLO}$ Undervoltage Lockout (UVLO) Threshold     1.9     V	R <sub>SW</sub> Switch "On" Resistance         I <sub>SW</sub> = 100 mA         1.0         2.0           I <sub>LEAK</sub> Switch Leakage Current         Switch Off, V <sub>SW</sub> = 5 V         1         5           T <sub>SD</sub> Thermal Shutdown         150         1           T <sub>HYS</sub> Thermal Hysteresis         20         20           η         Efficiency         Typical Application Circuit         86           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1,9	F <sub>SW</sub>	Switching Frequency		0.7	1.0	1.3	MHz
ILEAK         Switch Leakage Current         Switch Off, V <sub>SW</sub> = 5 V         1         5         μA           T <sub>SD</sub> Thermal Shutdown         150         °C           T <sub>HYS</sub> Thermal Hysteresis         20         °C           η         Efficiency         Typical Application Circuit         86         %           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1.9         V	I <sub>LEAK</sub>   Switch Leakage Current   Switch Off, V <sub>SW</sub> = 5 V   1   5     T <sub>SD</sub>   Thermal Shutdown   150     T <sub>HYS</sub>   Thermal Hysteresis   20     η   Efficiency   Typical Application Circuit   86     V <sub>UVLO</sub>   Undervoltage Lockout (UVLO) Threshold   1,9	I <sub>LIM</sub>	Switch Current Limit		250	300	400	mA
T <sub>SD</sub> Thermal Shutdown         150         °C           T <sub>HYS</sub> Thermal Hysteresis         20         °C           η         Efficiency         Typical Application Circuit         86         %           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1.9         V	T <sub>SD</sub> Thermal Shutdown         150           T <sub>HYS</sub> Thermal Hysteresis         20           η         Efficiency         Typical Application Circuit         86           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1,9	R <sub>SW</sub>	Switch "On" Resistance	I <sub>SW</sub> = 100 mA		1.0	2.0	Ω
THYS         Thermal Hysteresis         20         °C           η         Efficiency         Typical Application Circuit         86         %           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1.9         V	THYS         Thermal Hysteresis         20           η         Efficiency         Typical Application Circuit         86           V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold         1,9	I <sub>LEAK</sub>	Switch Leakage Current	Switch Off, V <sub>SW</sub> = 5 V		1	5	μΑ
η Efficiency Typical Application Circuit 86 %  V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold 1.9 V	η Efficiency Typical Application Circuit 86  V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold 1.9	T <sub>SD</sub>	Thermal Shutdown			150		°C
V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold 1.9 V	V <sub>UVLO</sub> Undervoltage Lockout (UVLO) Threshold	T <sub>HYS</sub>	Thermal Hysteresis		NF	20		°C
5,75		η	Efficiency	Typical Application Circuit	i	86		%
Vov-sw Output Clamp Voltage "Open LED" fault 29 V	Vov-sw Output Clamp Voltage "Open LED" fault 29		` ,		SILL	1,9		V
COMMENOUR ORNING	THIS DEVICE PLEASE NTATIVE FOR INFORMATION OF THE PRESENTATIVE PLEASE NOT REPRESENTATIVE PLEASE NOT REPRESENTATIVE POR INFORMATION OF THE PRESENTATIVE POR INFORMATION OF THE PROPERTY OF THE	V <sub>OV-SW</sub>	Output Clamp Voltage	"Open LED" fault	2 1	29		V
			S DEVICE PLEASENTA REPRESENTA	OMME YOU INFO				

# **TYPICAL CHARACTERISTICS**

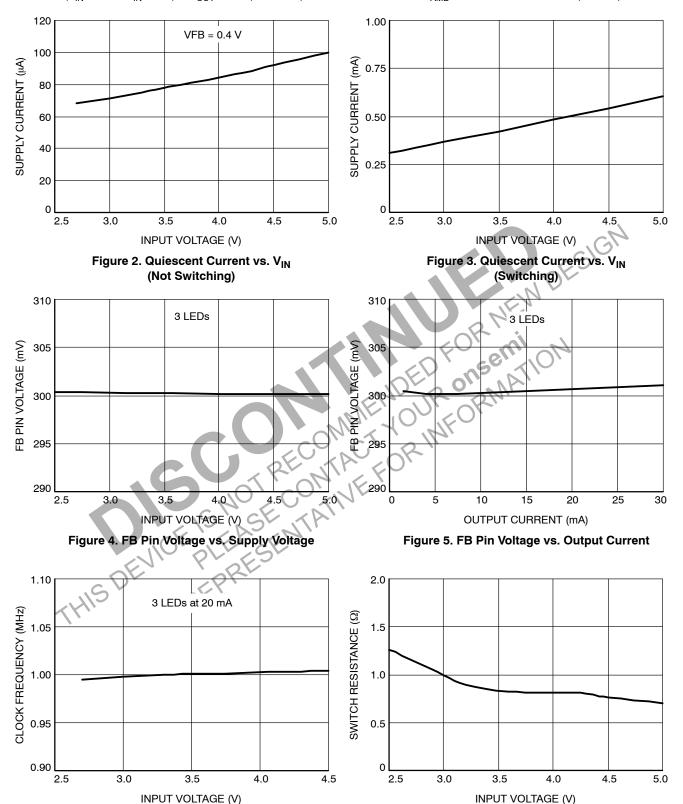


Figure 6. Switching Frequency vs. Supply Voltage

Figure 7. Switch ON Resistance vs. Input Voltage

# **TYPICAL CHARACTERISTICS**

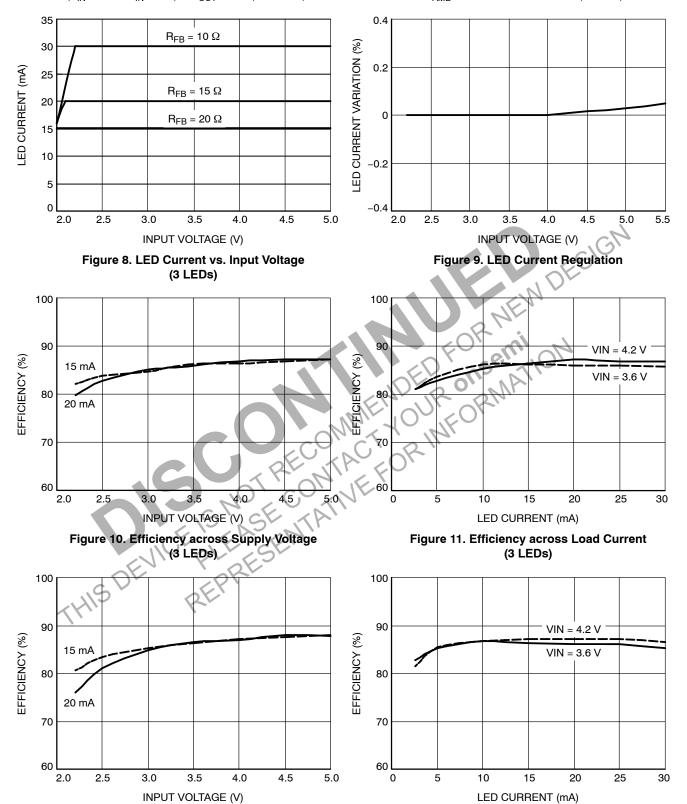
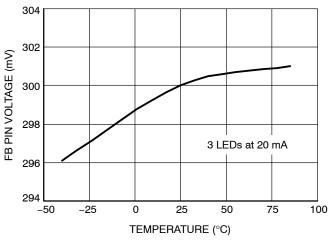


Figure 12. Efficiency across Supply Voltage (4 LEDs)

Figure 13. Efficiency across Load Current (4 LEDs)

# **TYPICAL CHARACTERISTICS**



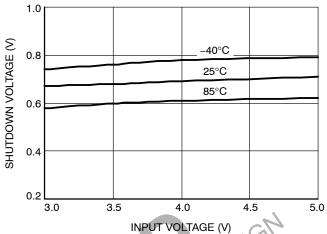
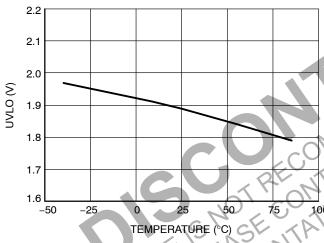


Figure 14. FB Pin Voltage vs. Temperature

Figure 15. Shutdown Voltage vs. Input Voltage



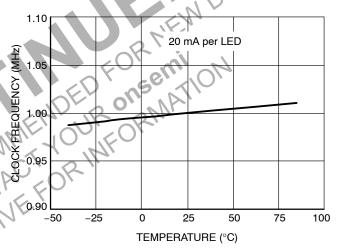
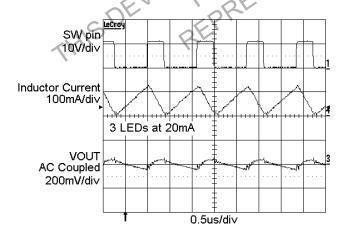


Figure 16. Under Voltage Lock Out vs. Temperature

Figure 17. Switching Frequency vs. Temperature



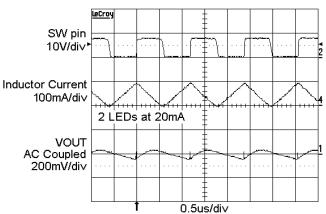


Figure 18. Switching Waveforms (3 LEDs in Series)

Figure 19. Switching Waveforms (2 LEDs in Series)

# **TYPICAL CHARACTERISTICS**

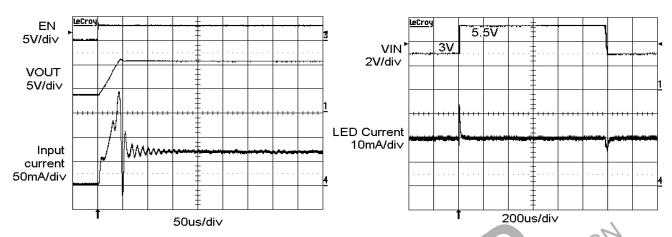
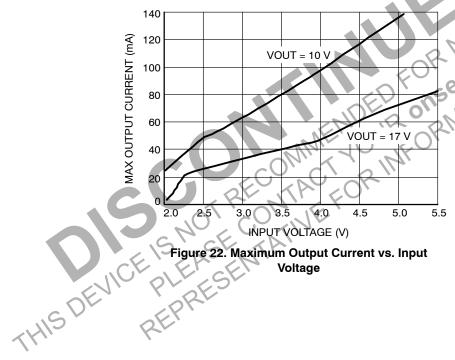


Figure 20. Power-up with 3 LEDs at 20 mA

Figure 21. Line Transient Response (3 V – 5.5 V)



#### **Pin Description**

VIN is the supply input for the internal logic. The device is compatible with supply voltages down to 2.2 V and up to 5.5 V. A small bypass ceramic capacitor of  $1\,\mu F$  is recommended between the VIN and GND pins near the device. The under-voltage lockout (UVLO) circuitry will place the device into an idle mode (not switching) whenever the supply falls below 1.9 V.

**SHDN** is the shutdown logic input. When the pin voltage is taken below 0.4 V, the device immediately enters shutdown mode, drawing nearly zero current. At voltages greater than 1.5 V, the device becomes fully enabled and operational.

**GND** is the ground reference pin. This pin should be connected directly to the ground plane on the PCB.

SW pin is the drain terminal of the internal low resistance power switch. The inductor and the Schottky diode anode should be connected to the SW pin. Traces going to the SW pin should be as short as possible with minimum loop area. This pin contains over-voltage circuitry which becomes active above 24 V. In the event of an "Open–Led" fault condition, the device will enter a low power mode and the SW pin will be clamped to approximately 30 V.

**FB** feedback pin is regulated at 0.3 V. A resistor connected between the FB pin and ground sets the LED current according to the formula:

$$I_{LED} = \frac{0.3 \text{ V}}{R1}$$

The lower LED cathode is connected to the FB pin.

**Table 4. PIN DESCRIPTIONS** 

Pin#	Name	Function
1	SW	Switch pin. This is the drain of the internal power switch.
2	GND	Ground pin. Connect the pin to the ground plane:
3	FB	Feedback pin. Connect to the last LED cathode.
4	SHDN	Shutdown pin (Logic Low). Set high to enable the driver.
5	VIN	Power Supply input.
	HISDEV	Shutdown pin (Logic Low). Set high to enable the driver.  Power Supply input.

#### **Device Operation**

The CAT4137 is a fixed frequency (1 MHz), low noise, inductive boost converter providing constant current to the load. A high voltage internal CMOS power switch is used to energize the external inductor. When the power switch is then turned off, the stored energy inductor is released into the load via the external Schottky diode.

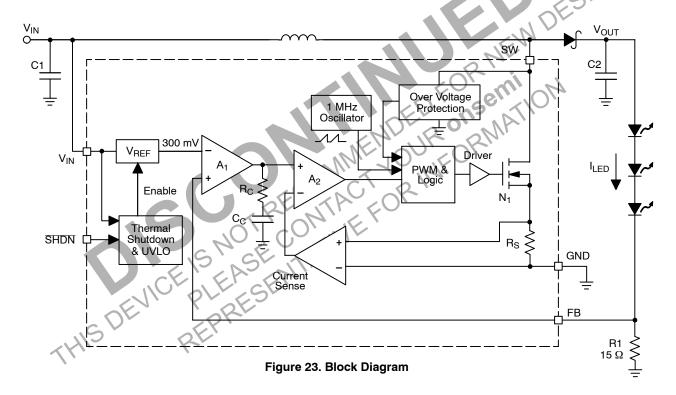
The on/off duty cycle of the power switch is internally adjusted and controlled to maintain a constant regulated voltage of 0.3 V across the external feedback resistor connected to the feedback pin (FB). The value of external resistor will accurately set the LED bias current accordingly (0.3 V/R1).

During the initial power-up stage, the duty cycle of the internal power switch is limited to prevent excessive in-rush currents and thereby provide a "soft-start" mode of operation.

While in normal operation, the device will comfortably deliver up to 30 mA of bias current into a string of up to 5 white LEDs.

In the event of a "Open-Led" fault condition, where the feedback control loop becomes open, the output voltage will continue to increase. Once this voltage exceeds 24 V, an internal protection circuit will become active and place the device into a very low power safe operating mode. In addition, an internal clamping circuit will limit the peak output voltage to 29 V. If this fault condition is repaired, the device will automatically resume normal operation.

Thermal overload protection circuitry has been included to prevent the device from operating at unsafe junction temperatures above 150°C. In the event of a thermal overload condition the device will automatically shutdown and wait till the junction temperatures cools to 130°C before normal operation is resumed.



# **Application Information External Component Selection**

#### **Capacitors**

The CAT4137 only requires small ceramic capacitors of  $1~\mu F$  on the input and  $0.22~\mu F$  on the output. The output capacitor should be rated at 30 V or greater. Under normal conditions, a  $1~\mu F$  input capacitor is sufficient. For applications with higher output power, a larger input capacitor of  $2.2~\mu F$  or  $4.7~\mu F$  may be appropriate. X5R and X7R capacitor types are ideal due to their stability across temperature range.

#### Inductor

A 22  $\mu$ H inductor is recommended for most of the CAT4137 applications. In cases where the efficiency is critical, inductances with lower series resistance are preferred. Several inductor types from various vendors can be used. Figure 24 shows how different inductor types affect the efficiency across the load range.

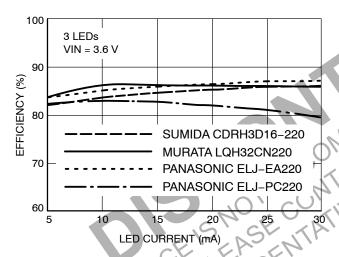


Figure 24. Efficiency for Various Inductors

#### **Schottky Diode**

The current rating of the Schottky diode must exceed the peak current flowing through it. The Schottky diode performance is rated in terms of its forward voltage at a given current. In order to achieve the best efficiency, this forward voltage should be as low as possible. The response time is also critical since the driver is operating at 1 MHz. Central Semiconductor Schottky CMDSH2-3 (200 mA rated) or the CMDSH-3 (100 mA rated) is recommended for most applications.

#### **LED Current Setting**

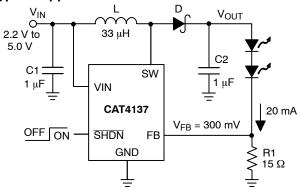
The LED current is set by the external resistor between the feedback pin (FB) and ground. The formula below gives the relationship between the resistor and the current:

$$R1 = \frac{0.3 \text{ V}}{\text{LED current}}$$

Table 5. RESISTOR R1 AND LED CURRENT

LED Current (mA)	R1 (Ω)
5	60
10/ 66	30
15	20
CM 150 BM	15
25	12
30	10

#### **Typical Applications**



L: Sumida CDRH3D16-330

D: Central CMDSH2-3 (rated 30 V)

C2: Taiyo Yuden GMK212BJ105KG-T (rated 35 V)

Figure 25. CAT4137 Driving Two LEDs

For best performance, a 33 µH inductor and a 1 µF output capacitor are recommended for 2-LED applications.

In 2-LED configuration, the CAT4137 can be powered from two AA alkaline cells or from a Li-ion battery.

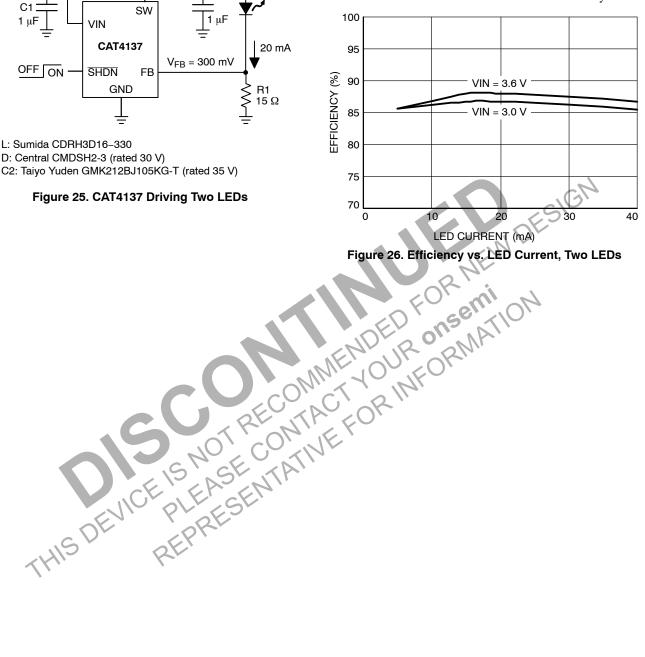


Figure 26. Efficiency vs. LED Current, Two LEDs

#### **Dimming Control**

There are several methods available to control the LED brightness.

## PWM Signal on the SHDN Pin

LED brightness dimming can be done by applying a PWM signal to the  $\overline{SHDN}$  input. The LED current is repetitively turned on and off, so that the average current is proportional to the duty cycle. A 100% duty cycle, with  $\overline{SHDN}$  always high, corresponds to the LEDs at nominal current. Figures 27 and 28 show 1 kHz and 4 kHz signals with a 50% duty cycle applied to the  $\overline{SHDN}$  pin. The PWM frequency range is from 100 Hz to 10 kHz. The recommended PWM frequency range is from 100 Hz to 4 kHz.

# Switching Waveforms PWM on SHDN

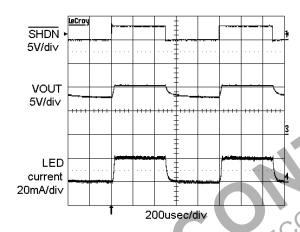


Figure 27, PWM at 1 kHz

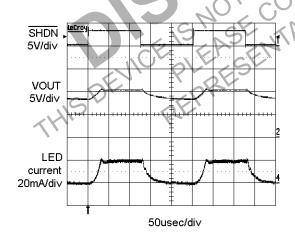


Figure 28. PWM at 4 kHz

#### Filtered PWM Signal

A filtered PWM signal can be used as a variable DC voltage that can be used to control the LED current. Figure 29 shows the PWM control circuitry connected to the CAT4137 FB pin. The PWM signal has a voltage swing of 0 V to 2.5 V. The LED current can be dimmed within a range from 0 to 22 mA. The PWM signal frequency can vary from very low frequency up to 100 kHz.

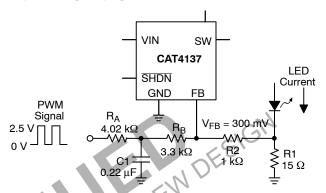


Figure 29. Circuit for Filtered PWM Signal

A PWM signal at 0 V DC, or a 0% duty cycle, results in a max LED current of about 22 mA. A PWM signal with a 100% duty cycle results in an LED current of 0 mA.

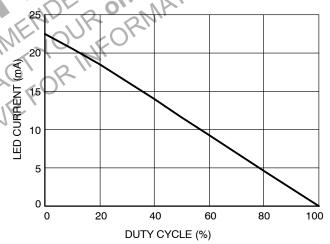


Figure 30. LED Current vs. Duty Cycle

#### **Open LED Protection**

In the event of an "Open LED" fault condition, the CAT4137 will continue to boost the output voltage with maximum power until the output voltage reaches approximately 24 V. Once the output exceeds this level, internal circuitry immediately places the device into a very low power mode where the total input power consumed is less than 10 mW.

Figure 31. Open LED Protection

In low power mode, the input supply current will typically drop to 2 mA. An internal clamping circuit will limit the subsequent output voltage to approximately 29 V. This operating mode eliminates the need for any external protection zener diode. This protection scheme also fully protects the device against any malfunction in the external Schottky diode (open-circuit).

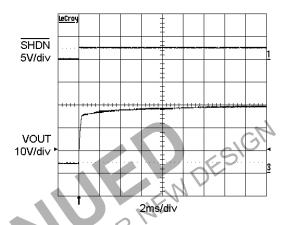


Figure 32. Open LED Power-up Waveforms

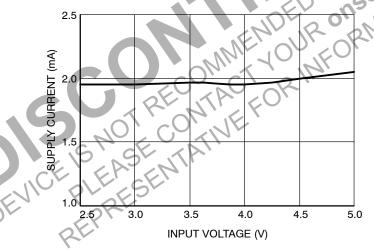
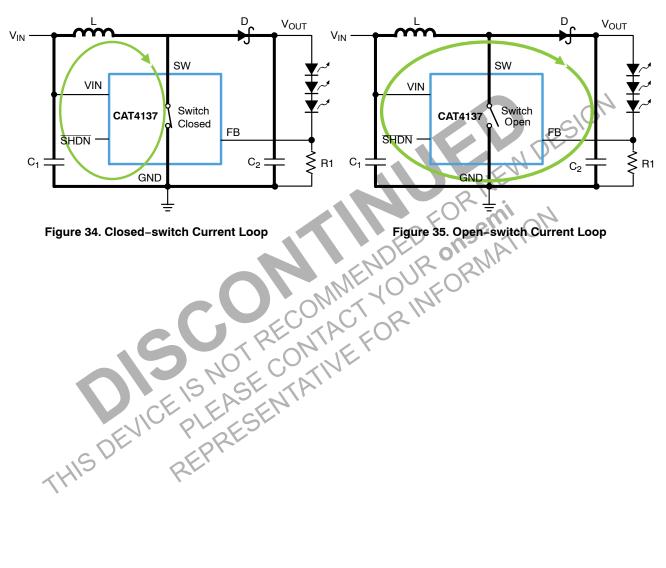


Figure 33. Open LED Supply Current vs. VIN

#### **Board Layout**

The CAT4137 is a high-frequency switching regulator. Traces carrying high-frequency switching current have to be carefully layout on the board in order to minimize EMI, ripple and noise in general. The thicker lines shown on Figure 34 indicate the switching current path. All these traces have to be short and wide enough to minimize the parasitic inductance and resistance. The loop shown on Figure 34 corresponds to the current path when the CAT4137 internal switch is closed. On Figure 35 is shown the current loop when the CAT4137 switch is open. Both loop areas should be as small as possible.

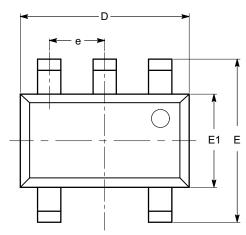
Capacitor C1 has to be placed as close as possible to the VIN pin and GND. The capacitor C2 has to be connected separately to the top LED anode. A ground plane under the CAT4137 allows for direct connection of the capacitors to ground. The resistor R1 must be connected directly to the GND pin of the CAT4137 and not shared with the switching current loops and any other components.



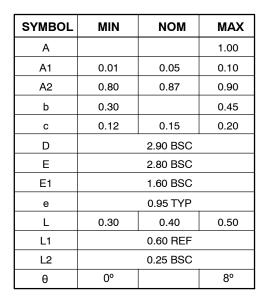


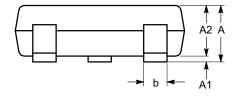
TSOT-23, 5 LEAD CASE 419AE-01 ISSUE O

**DATE 19 DEC 2008** 

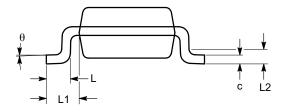


ТОР	VIEW	





SIDE VIEW



**END VIEW** 

#### Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-193.

DOCUMENT NUMBER:	98AON34392E Electronic versions are uncontrolled except when accessed directly from the Do Printed versions are uncontrolled except when stamped "CONTROLLED COPY"		
DESCRIPTION:	TSOT-23, 5 LEAD		PAGE 1 OF 1

onsemi and ONSEMi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales